Attorney Refere	ence	
-----------------	------	--

## DECLARATION FOR UNITED STATES PATENT APPLICATION, POWER OF ATTORNEY, DESIGNATION OF CORRESPONDENCE ADDRESS

As a below named inventor, I hereby declare that my residence, post office address and citizenship are as stated below next to my name, and that I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

SEMICONDUCTOR LIGHT EMITTING DEVICE

,

the specification of which

] is attached her ] was filed on and was amend x] was filed under Serial No. PC		Treaty on July	[if applica				
claims. acknowledge the	at I have reviewed and duty to disclose to the Pa fined in Title 37, Code of	atent and Tradema	ark Office infor				
I hereby claim patent or inventor's pertificate having a	n foreign priority benefits s certificate listed below a filing date before that of	s under Title 35, and have also ide	United States entified below a	ny foreign app	of any for plication f	eign applic or patent o	ation(s) for r inventor's
	Number		Priority	Claimed	Yes	No	
Country	Date Filed			٠		NO	
Japan 2	2004-205095	July 12,	2004		Yes		<del></del>
		•			•		
States Patent and (Reg. No. 38,075),	appoint the following atto Trademark Office conn , Phillip G. Avruch (Re all correspondence to:	ected therewith:	Steven M. Ra	bin (Reg. No.	29,102)	ousiness in , Robert H.	the United Berdo, Jr.
		*239	95*			·	
		239 Patent Trade					
				٠			
undersigned's ass domestic attorney, Trademark Office undersigned. In the herein will be so no	ned hereby authorizes to signee, if any, and/or, if patent attorney, patent regarding this applicate ne event of a change in to otified by the undersigne	the undersigned agent, or patent realism without direction without direction managers. It is not the person(s) from d.	is not a reside epresentative a ect communica whom instruct	lent of the Ur is to any actio ition between ions may be to	nited Stat on to be ta or the U.S aken, the	es, the undaken in the S. attorney U.S. attorn	dersigned's Patent and 's and the eys named
information and be willful false statem the United States issued thereon.	are that all statements nelief are believed to be nents and the like so made Code and that such willf	true; and further de are punishable ul false statement	that these state by fine or impose s may jeopardi	tements were risonment, or lize the validity	made wi both, und of the ap	th the know er §1001 of plication or	wledge that f Title 18 of any patent
Signature:	Firokazu Asah Hirokaz	ara)	Date:	Septeml	rer 1	2	_, 200 <u>5</u> _
Citizenship: Japa Residence and Po	an est Office Address:	c/o ROHM ( Ukyo-ku, 1	CO., LTD.	, 21, Sai	in Mi:	zosaki-	cho,
Sinnatura: M	itsuhiko Satar		Date:	September	20		2005
Second Joint Inver Citizenship: <b>Ja</b> pa	ntor: Mitsuhi	ko SAKAI c/o ROHM Ukyo-ku,	CO., LTD.	, 21, Sai	in Mi	zosaki-	cho,
	Takio nis	hita	Data	Septe	nber	20	. 200
Signature:Third Joint Invento Citizenship: Jap. Residence and Po	or: Toshio an ost Office Address:	NISHIDA c/o ROHM Ukyo-ku,	CO. LTD.	. 21. Sa	iin Mi	zosaki-	-cho,
	Josephi So	nobe	Date:	September	~ 20		, 2005
Signature:	n	SONOBE c/o ROHM C Ukyo-ku, K	O., LTD.,	21, Sai:	in Miz	osaki-c	ho,